Super Fast Recovery Diode

RFV15TG6S Data Sheet

Serise

Standard Fast Recovery

Application

General rectification

For PFC

(CCM: Continuous Current Mode)

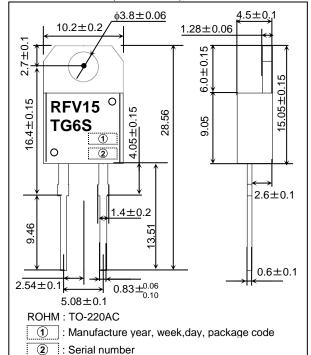
Features

- 1) Hyper fast recovery / Hard recovery type
- 2) Ultra low switching loss
- 3) High current overload capacity

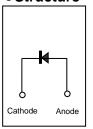
Construction

Silicon epitaxial planar type

●Dimensions (Unit : mm)



Structure



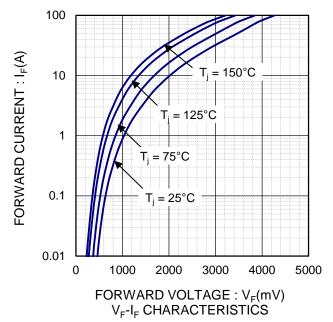
● Absolute Maximum Ratings (T_a= 25°C)

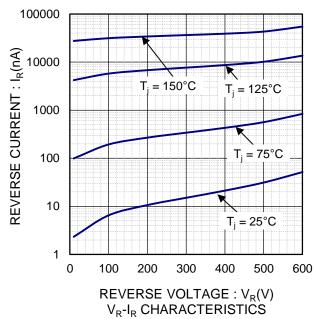
Parameter	Symbol	Conditions	Limits	Unit
Repetitive peak reverse voltage	V_{RM}	Duty≦0.5	600	V
Reverse voltage	V_R	Direct reverse voltage	600	V
Average current	l _o	60Hz half sin wave , resistive load	15	Α
Non-repetitive forward surge current	I _{FSM}	60Hz half sin wave, one cycle, non-repetitive at T_j =25°C	150	Α
Operating junction temperature	Tj	-	150	°C
Storage temperature	T _{stg}	-	-55 to +150	°C

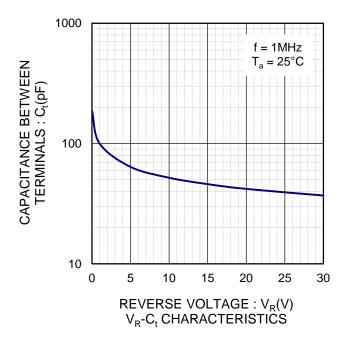
●Electrical Characteristics (T_j = 25°C)

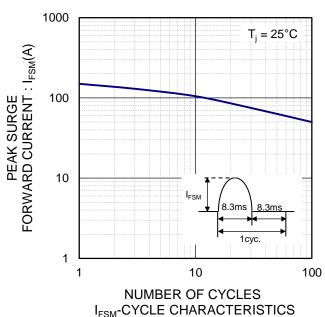
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
Forward voltage	V _F	I _F =15A	T _j =25°C	1.6	2.3	2.8	V
			T _j =125°C	-	1.55	-	V
Reverse current	I _R	V _R =600V	T _j =25°C	-	0.03	10	μΑ
			T _j =125°C	-	10	200	μΑ
Reverse recovery time	trr	I _F =0.5A, I _R =1A, Irr=0.25×I _R		-	20	30	ns
		$I_F=15A$, $V_R=400V$, $dI_F/dt=-200A/\mu s$		-	30	50	ns
Reverse recovery current	I _{Rp}	I _F =15A, V _R =400V	T _i =125°C	-	6.5	-	Α
Reverse recovery charges	Qrr	dI _F /dt=-200Aμs	1 _j =125 C	-	200	-	nC
Forward recovery time	tfr	I _F =15A, dI _F /dt=200A/μs,		-	150	-	ns
Forward recovery voltage	V_{Fp}	$V_{FR}=1.1xV_{Fmax}$		-	5.5	-	V
Thermal resistance	R _{th} (j-a)	Junction to ambient		-	-	2.0	°C/W
	R _{th} (j-c)	Junction to case		1	-	1.2	°C/W

•Electrical Characteristic Curves

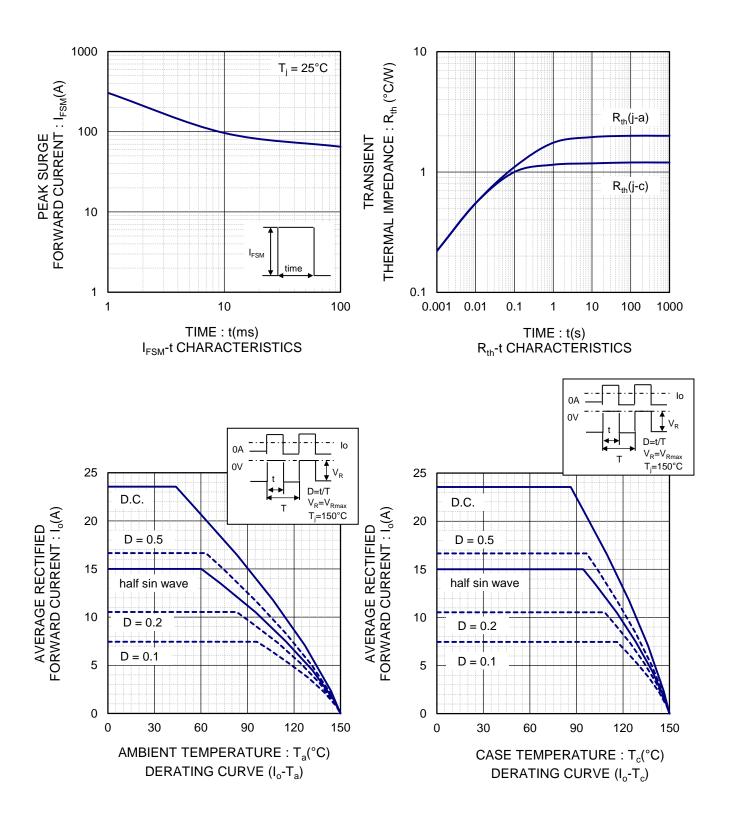




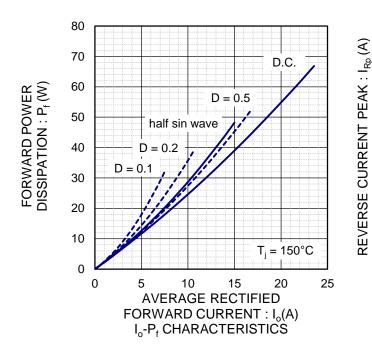


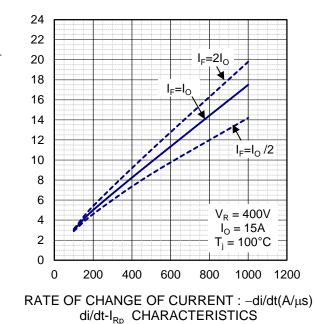


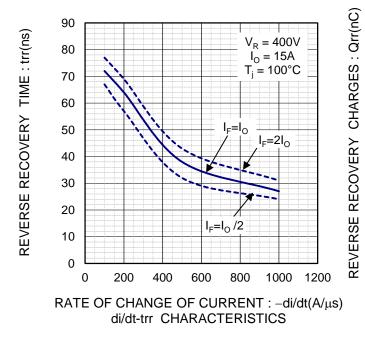
•Electrical characteristic curves

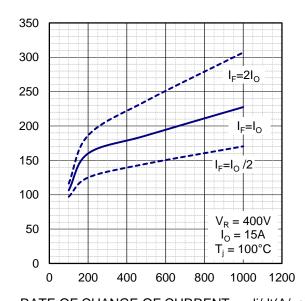


•Electrical characteristic curves



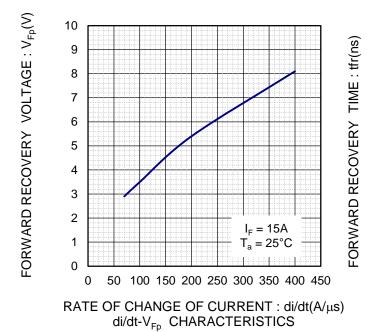






RATE OF CHANGE OF CURRENT : -di/dt(A/μs) di/dt-Qrr CHARACTERISTICS

•Electrical characteristic curves



240
240
1_F = 15A
T_a = 25°C

220
200
180
160
140
120
0 50 100 150 200 250 300 350 400 450

RATE OF CHANGE OF CURRENT : $di/dt(A/\mu s)$ di/dt-tfr CHARACTERISTICS

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